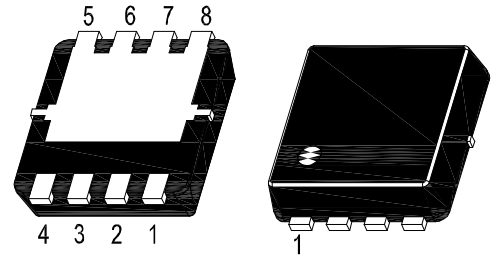
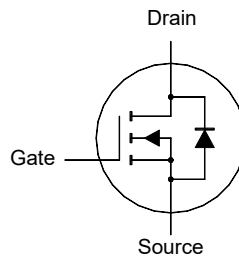


# WTM304N065L-AH

## N-Channel Enhancement Mode MOSFET

### Features

- AEC-Q101 Qualified
- Surface-mounted package
- Halogen and Antimony Free(HAF), RoHS compliant



1. Source 2. Source 3. Source 4. Gate  
5. Drain 6. Drain 7. Drain 8. Drain  
DFN3030 Plastic Package

### Applications

- synchronous buck converter

### Key Parameters

Parameter	Value	Unit
$BV_{DSS}$	40	V
$R_{DS(ON)} \text{ Max}$	6.5 @ $V_{GS} = 10 \text{ V}$	m $\Omega$
	9 @ $V_{GS} = 4.5 \text{ V}$	
$V_{GS(th)} \text{ typ}$	1.4	V
$Q_g \text{ typ}$	59 @ $V_{GS} = 10 \text{ V}$	nC

### Absolute Maximum Ratings(at $T_a = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	$V_{DS}$	40	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Drain Current - Continuous	$I_D$	40	A
$T_c = 25^\circ\text{C}$		31	
$T_c = 100^\circ\text{C}$			
Peak Drain Current, Pulsed <sup>1)</sup>	$I_{DM}$	140	A
Single-Pulse Avalanche Current	$I_{AS}$	32.9	A
Single-Pulse Avalanche Energy <sup>2)</sup>	$E_{AS}$	54.1	mJ
Power Dissipation	$P_D$	36.7	W
$T_c = 25^\circ\text{C}$			
Operating Junction and Storage Temperature Range	$T_j, T_{stg}$	- 55 to + 150	$^\circ\text{C}$

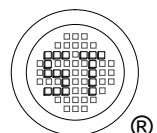
### Thermal Characteristics

Parameter	Symbol	Max.	Unit
Thermal Resistance from Junction to Case	$R_{\theta JC}$	3.4	$^\circ\text{C/W}$
Thermal Resistance from Junction to Ambient <sup>3)</sup>	$R_{\theta JA}$	75	$^\circ\text{C/W}$

<sup>1)</sup> Pulse Test: Pulse Width  $\leq 100 \mu\text{s}$ , Duty Cycle  $\leq 2\%$ , Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)} = 150^\circ\text{C}$ .

<sup>2)</sup> Limited by  $T_{J(MAX)}$ , starting  $T_J = 25^\circ\text{C}$ ,  $L = 0.1 \text{ mH}$ ,  $R_g = 25 \Omega$ ,  $I_D = 32.9 \text{ A}$ ,  $V_{GS} = 10 \text{ V}$ .

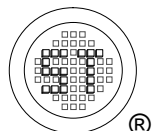
<sup>3)</sup> Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate in still air.



# WTM304N065L-AH

Characteristics at  $T_a = 25^\circ\text{C}$  unless otherwise specified

Parameter	Symbol	Min.	Typ.	Max.	Unit
<b>STATIC PARAMETERS</b>					
Drain-Source Breakdown Voltage at $I_D = 250\ \mu\text{A}$	$BV_{DSS}$	40	-	-	V
Drain-Source Leakage Current at $V_{DS} = 32\ \text{V}$	$I_{DSS}$	-	-	1	$\mu\text{A}$
Gate-Source Leakage Current at $V_{GS} = \pm 20\ \text{V}$	$I_{GSS}$	-	-	$\pm 100$	nA
Gate-Source Threshold Voltage at $V_{DS} = V_{GS}$ , $I_D = 250\ \mu\text{A}$	$V_{GS(th)}$	1	-	2.5	V
Drain-Source On-State Resistance at $V_{GS} = 10\ \text{V}$ , $I_D = 10\ \text{A}$ at $V_{GS} = 4.5\ \text{V}$ , $I_D = 5\ \text{A}$	$R_{DS(on)}$	- -	5.1 -	6.5 9	m $\Omega$
<b>DYNAMIC PARAMETERS</b>					
Forward Transconductance at $V_{DS} = 5\ \text{V}$ , $I_D = 5\ \text{A}$	$g_{fs}$	-	27	-	S
Gate Resistance at $V_{GS} = 0\ \text{V}$ , $V_{DS} = 0\ \text{V}$ , $f = 1\ \text{MHz}$	$R_g$	-	0.4	-	$\Omega$
Input Capacitance at $V_{GS} = 0\ \text{V}$ , $V_{DS} = 25\ \text{V}$ , $f = 1\ \text{MHz}$	$C_{iss}$	-	3303	-	pF
Output Capacitance at $V_{GS} = 0\ \text{V}$ , $V_{DS} = 25\ \text{V}$ , $f = 1\ \text{MHz}$	$C_{oss}$	-	223	-	pF
Reverse Transfer Capacitance at $V_{GS} = 0\ \text{V}$ , $V_{DS} = 25\ \text{V}$ , $f = 1\ \text{MHz}$	$C_{rss}$	-	196	-	pF
Gate Charge Total at $V_{DS} = 20\ \text{V}$ , $V_{GS} = 10\ \text{V}$ , $I_D = 10\ \text{A}$ at $V_{DS} = 20\ \text{V}$ , $V_{GS} = 4.5\ \text{V}$ , $I_D = 10\ \text{A}$	$Q_g$	- -	59 29	- -	nC
Gate to Source Charge at $V_{DS} = 20\ \text{V}$ , $V_{GS} = 10\ \text{V}$ , $I_D = 10\ \text{A}$	$Q_{gs}$	-	7.6	-	nC
Gate to Drain Charge at $V_{DS} = 20\ \text{V}$ , $V_{GS} = 10\ \text{V}$ , $I_D = 10\ \text{A}$	$Q_{gd}$	-	10.2	-	nC
Turn-On Delay Time at $V_{GS} = 10\ \text{V}$ , $V_{DS} = 15\ \text{V}$ , $I_D = 1\ \text{A}$ , $R_g = 3.3\ \Omega$	$t_{d(on)}$	-	15.2	-	ns
Turn-On Rise Time at $V_{GS} = 10\ \text{V}$ , $V_{DS} = 15\ \text{V}$ , $I_D = 1\ \text{A}$ , $R_g = 3.3\ \Omega$	$t_r$	-	8.8	-	ns
Turn-Off Delay Time at $V_{GS} = 10\ \text{V}$ , $V_{DS} = 15\ \text{V}$ , $I_D = 1\ \text{A}$ , $R_g = 3.3\ \Omega$	$t_{d(off)}$	-	74	-	ns
Turn-Off Fall Time at $V_{GS} = 10\ \text{V}$ , $V_{DS} = 15\ \text{V}$ , $I_D = 1\ \text{A}$ , $R_g = 3.3\ \Omega$	$t_f$	-	7	-	ns
<b>Body-Diode PARAMETERS</b>					
Drain-Source Diode Forward Voltage at $I_S = 1\ \text{A}$ , $V_{GS} = 0\ \text{V}$	$V_{SD}$	-	-	1	V
Body-Diode Continuous Current	$I_S$	-	-	40	A
Body-Diode Continuous Current, Pulsed	$I_{SM}$	-	-	140	A



## Electrical Characteristics Curves

Fig. 1 Typical Output Characteristic

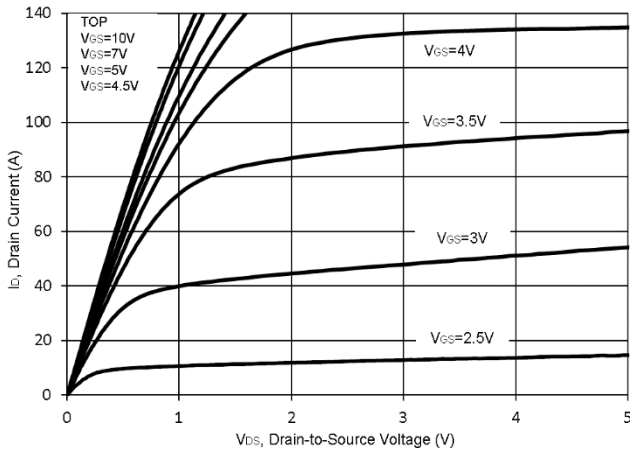


Fig. 2 Typical Transfer Characteristic

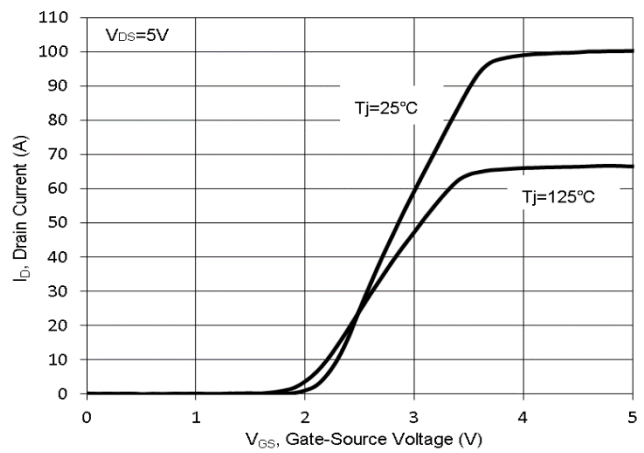


Fig. 3 on-Resistance vs. Gate Voltage

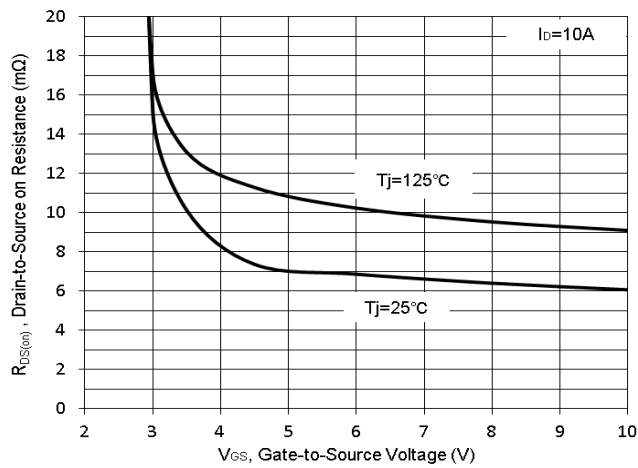


Fig. 4 on-Resistance vs. Tj

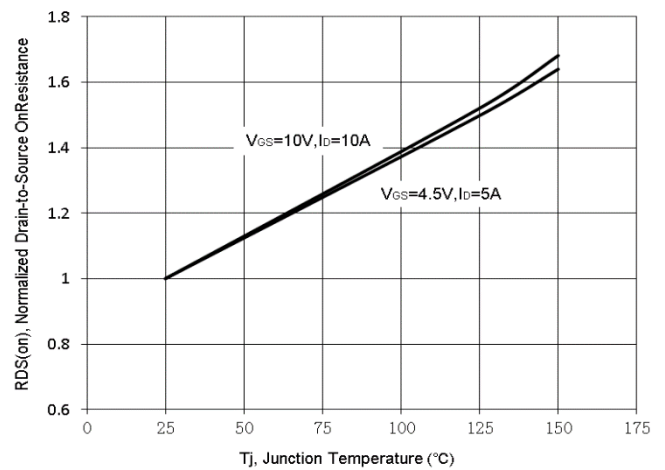


Fig. 5 on-Resistance vs. Drain Current

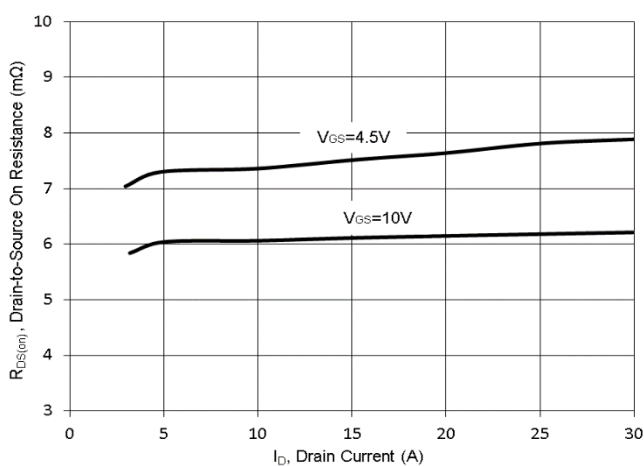
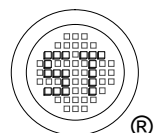
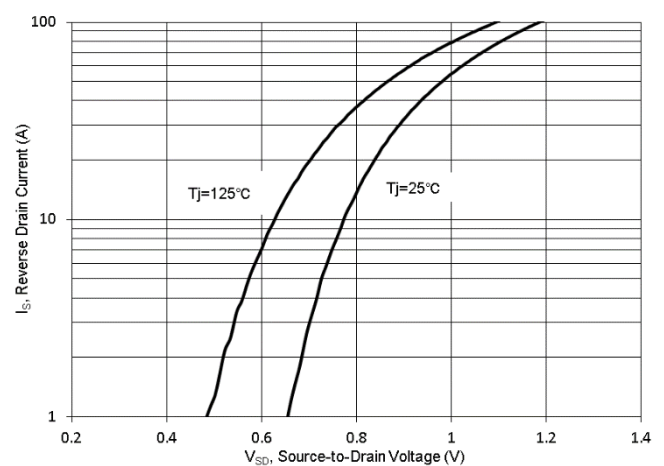


Fig. 6 Typical Body-Diode Forward Characteristic



## Electrical Characteristics Curves

Fig. 7  $V_{(BR)DSS}$  vs. Junction Temperature

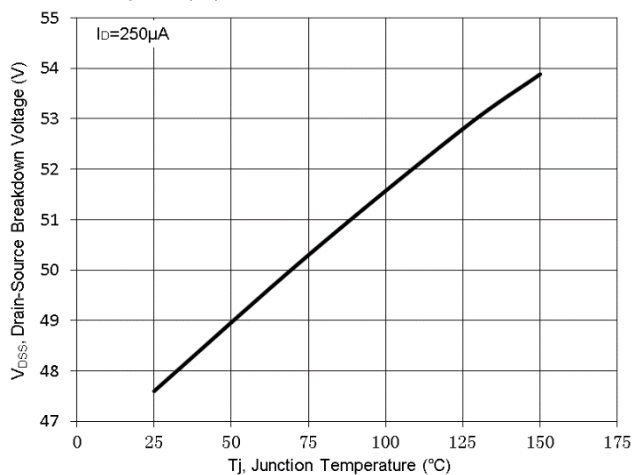


Fig. 8 Gate Threshold Variation vs.  $T_J$

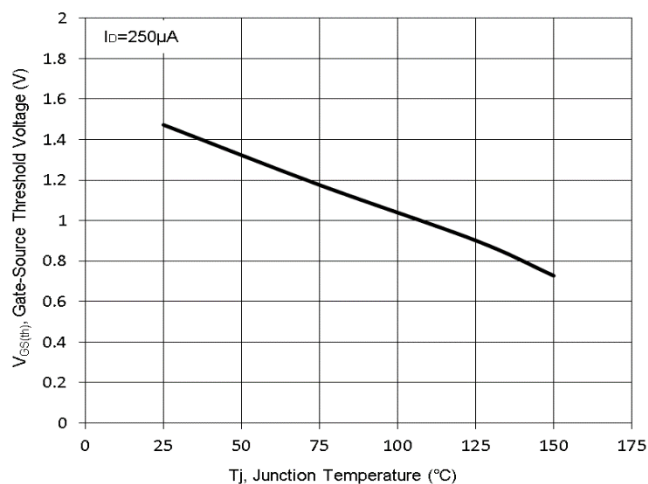


Fig. 9 Typical Junction Capacitance

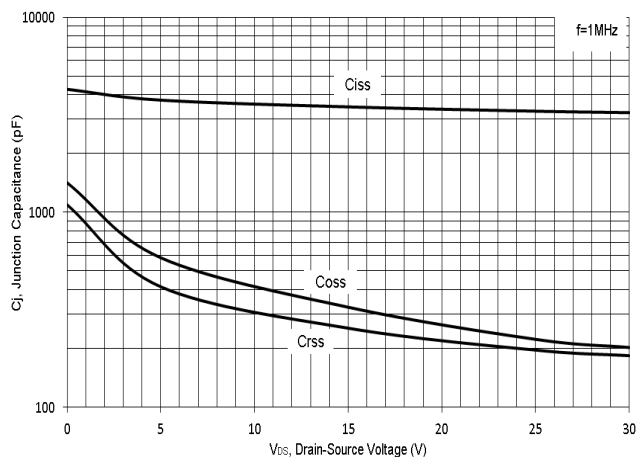


Fig. 10 Gate Charge

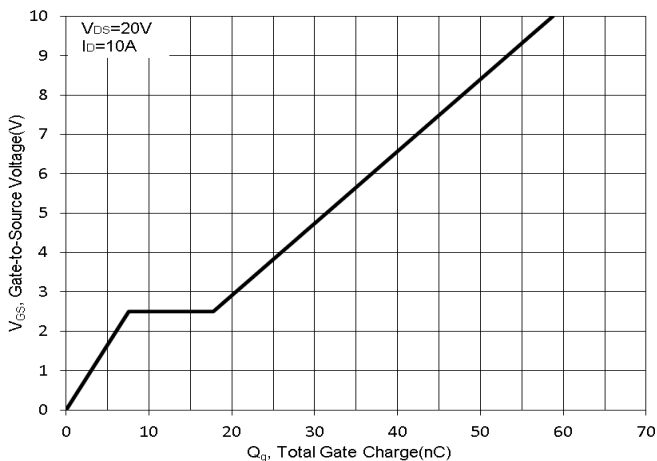


Fig. 11 Drain-Source Leakage Current

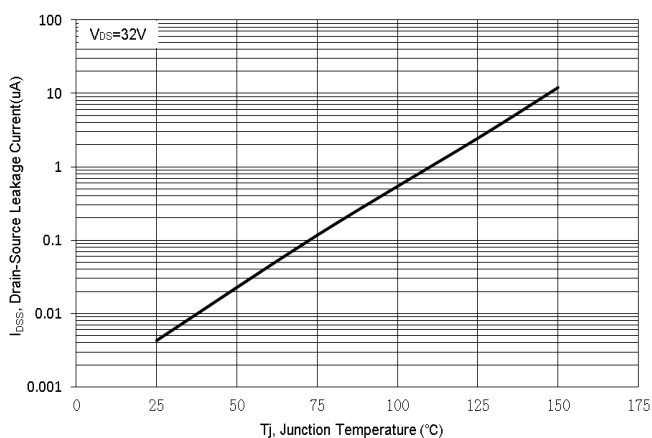
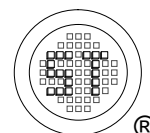
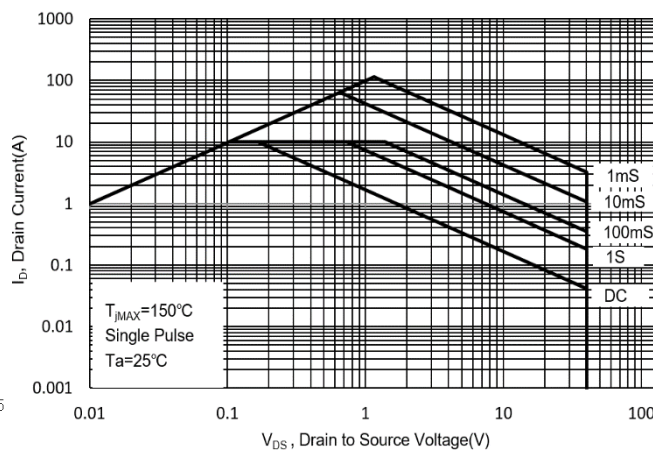


Fig. 12 Safe Operation Area



## Test Circuits

Fig.1-1 Switching times test circuit

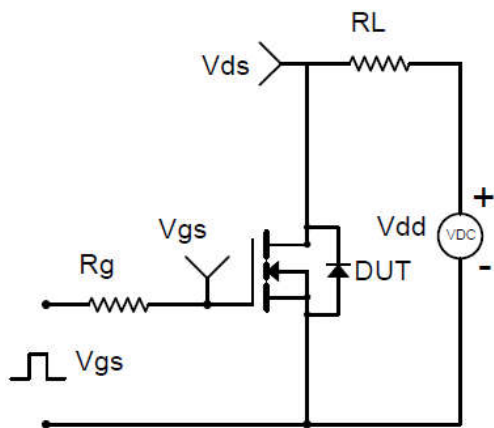


Fig.1-2 Switching Waveform

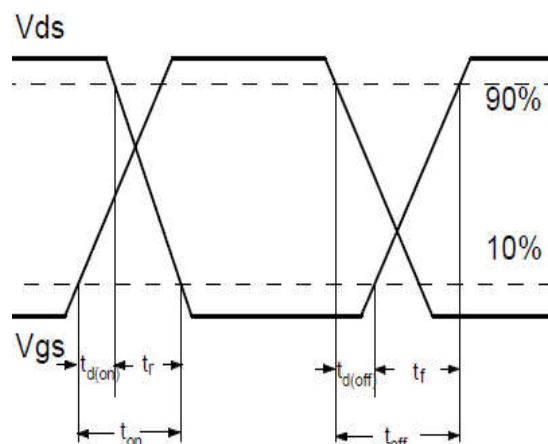


Fig.2-1 Gate charge test circuit

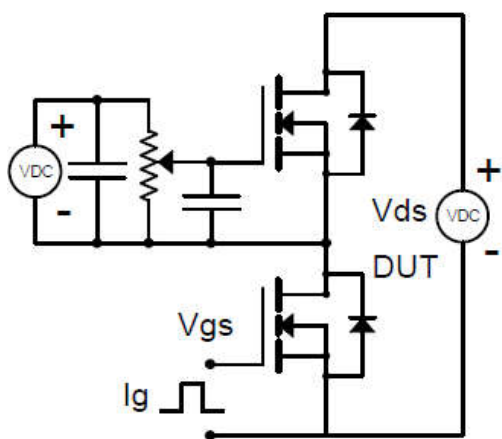


Fig.2-2 Gate charge waveform

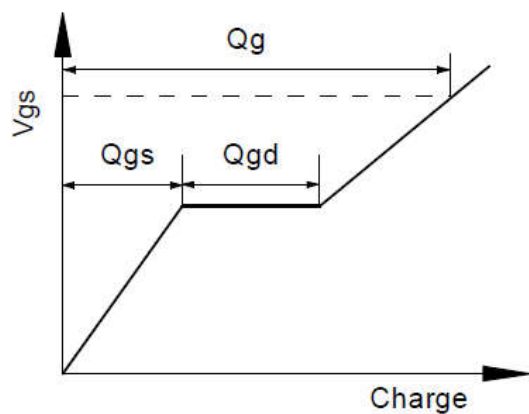


Fig.3-1 Avalanche test circuit

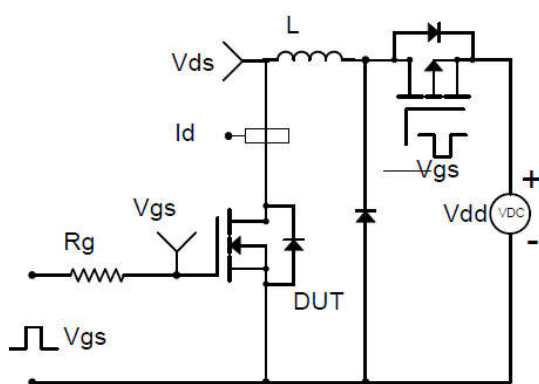
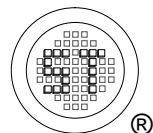
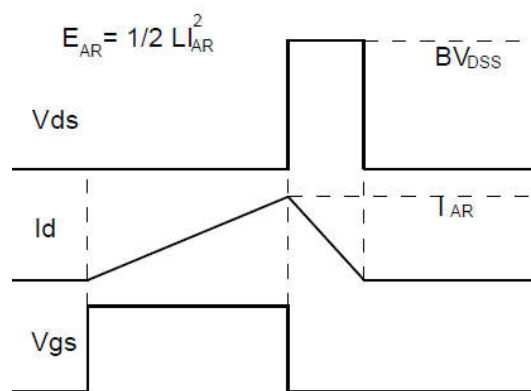


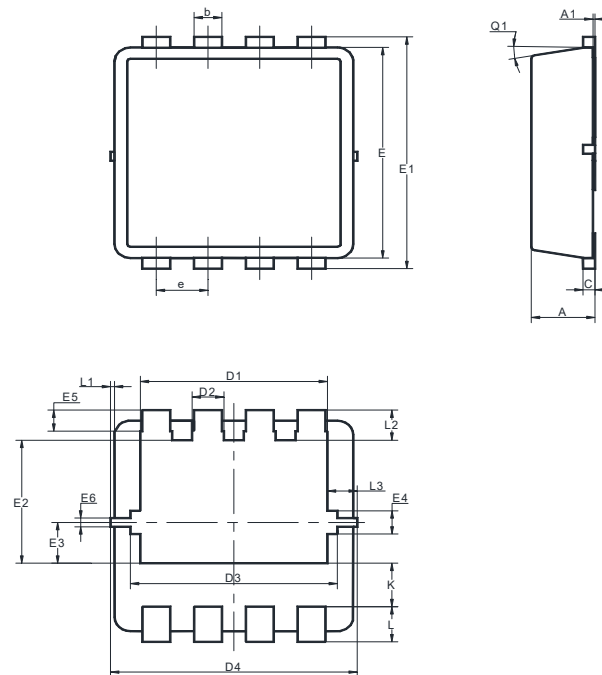
Fig.3-2 Avalanche waveform



# WTM304N065L-AH

## Package Outline Dimensions (Units: mm)

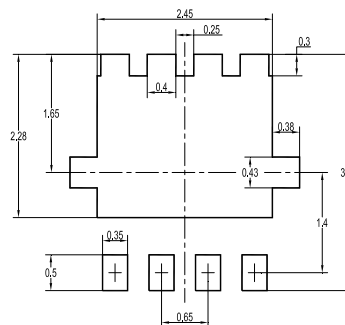
DFN3030



UNIT	A	A1	b	c	D1	D2	D3	D4	E	E1	E2	E3	E4
mm	0.9	0.05	0.35	0.25	2.6	0.5	2.7	3.2	3.1	3.3	1.85	0.68	0.43
	0.7	0	0.24	0.1	2.4	0.3	2.5	3	2.9	3.1	1.65	0.48	0.23

UNIT	E5	E6	e	K	L	L1	L2	L3	θ1
mm	0.4	0.25	0.7	0.72	0.5	0.1	0.53	0.475	12°
	0.2	0.15	0.6	0.52	0.3	0	0.33	0.275	0°

## Recommended Soldering Footprint



## Packing information

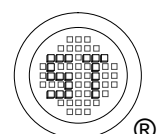
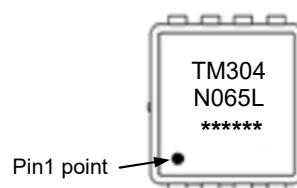
Package	Tape Width (mm)	Pitch		Reel Size		Per Reel Packing Quantity
		mm	inch	mm	inch	
DFN3030	12	8 ± 0.1	0.315 ± 0.004	330	13	5,000

## Marking information

" TM304N065L " = Part No.

" \*\*\*\*\* " = Date Code Marking

Font type: Arial



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